Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
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Glass

**Overall Length:** 

0.350 inches

# **Terminal Length:**

0.975 inches

### **Overall Diameter:**

0.145 inches

#### **Mounting Method:**

Terminal

### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

200.0 reverse voltage, peak and 1.1 on voltage, forward voltage drop, dc

#### **Current Rating Per Characteristic:**

1.20 amperes forward current, average absolute and 3.00 amperes forward current, average peak

### Capacitance Rating In Picofarads:

320.0

# Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

### **Test Data Document:**

84347-181-655 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### Terminal Type And Quantity:

2 uninsulated wire lead

#### Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

No

Fiig:

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